# ASSP

## **CMOS**

# **30 MHz 8-bit A/D Converter**

# **MB40C238**

### DESCRIPTION

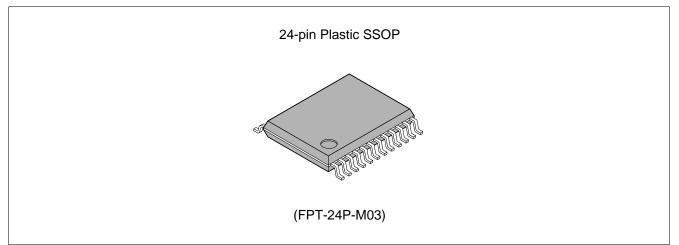
MB40C238 is a high-speed converter using a fast CMOS technology.

: 24-pin SSOP

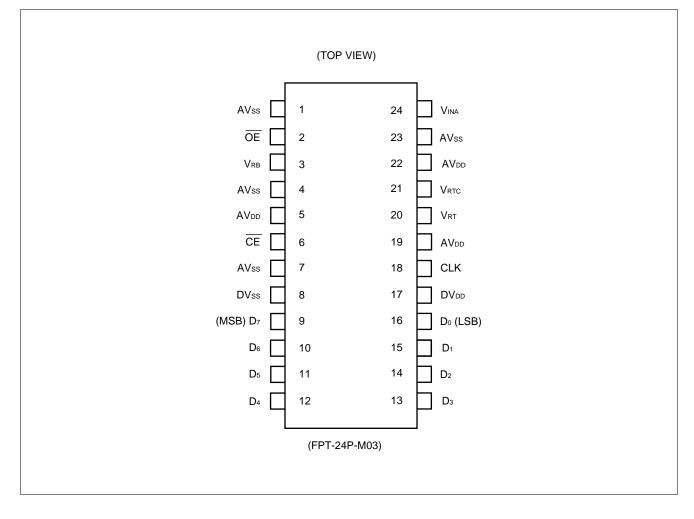
#### FEATURES

- Resolution : 8 bit • Linearity error : ±0.2% (standard) Differential linearity error : ±0.12% (standard) Maximum conversion rate : 30 MSPS (minimum) Power supply voltage : +3.0 V (single) • Digital input voltage range : 3 V CMOS level • Digital output voltage range : 3 V CMOS level compatible (tristate output) • Analog input voltage range : 0 to 2.0 V (1.2 to 1.8 Vp-p) Analog input capacitance
- Additional features
- : 15 pF (standard)
- Power dissipation
- : 50 mW (standard: including reference current)
- : VRT voltage adjustment amp (VRT = 1.2 to 2.0 V) Power saving capacity (also reference current set to OFF: 0.5 mW or less) High impedance output
- Package

#### ■ PACKAGE



#### ■ PIN ASSIGNMENT



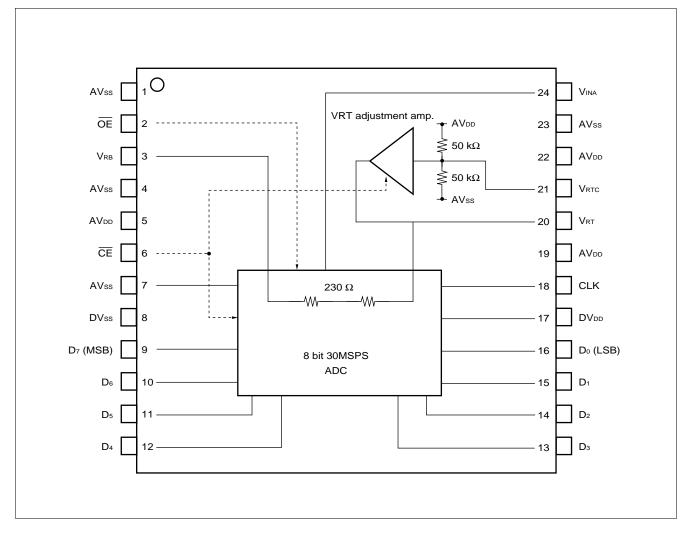
#### ■ PIN DESCRIPTION

Pin No.	Symbol	Description
5, 19, 22	AVdd	Analog power supply (+3.0 V)
17	DVdd	Digital power supply (+3.0 V)
1, 4, 7, 23	AVss	Analog power supply ground pin (0 V)
8	DVss	Digital power supply ground pin (0 V)
9, 10, 11, 12, 13, 14, 15, 16	D7 to D0	Digital output pin (D7: MSB, D0: LSB)
18	CLK	Clock input pin
24	Vina	A/D converter analog input pin Input range is VRB to VRT (0 to 1.5 V: standard)
21	Vrtc	VRT voltage adjustment amp input pin (VRTC: 1.5 V is output when opened.)
20	Vrt	Reference voltage output pin on top side. The voltage fed to $V_{RTC}$ is output. (1.5 V: standard)
3	Vrb	Reference voltage input pin on bottom side (0 V: standard)
6	CE	Input pin for toggling standby function. Input high signal brings the ADC and reference voltage circuit.
2	OE	Input pin for toggling output high impedance function. Input high signal brings the ADC output high impedance state.

Note: The values in parentheses are standard.

# MB40C238

BLOCK DIAGRAM



#### ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ra	l Init	
Parameter	Symbol	Min.	Max.	Unit
Power supply voltage	AVdd, DVdd	-0.3	+7.0	V
Input voltage (analog/digital)	CLK, Vina, Vrtc, Vrb	-0.3	AVDD+0.3	V
Output voltage	D <sub>0</sub> to D <sub>7</sub>	-0.3	DVDD+0.3	V
Output voltage	Vrt	-0.3	AVpd+0.3	V
Storage temperature	Tstg	-55	+125	°C

**WARNING:** Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

#### ■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Value			Unit	
Falameter	Symbol	Min.	Тур.	Max.	- Unit	
	AVdd	2.70	3.00	3.60	V	
Power supply voltage	DVdd	2.70	3.00	3.60	V	
	AVDD – DVDD	0.0	_	0.2	V	
Analog input voltage	VINA	Vrb	_	Vrt	V	
Analog reference voltage: T	Vrtc	1.2	1.5	2.0	V	
Analog reference voltage: B	Vrb	0.0	_	0.8	V	
Analog reference voltage range	Vrt – Vrb	1.2	1.5	1.8	V	
Digital "H" level input voltage	Vihd	2.3	_	_	V	
Digital "L" level input voltage	Vild		_	0.5	V	
Digital input current	DI		_	5	μA	
Clock frequency	fclk	0.5	_	30	MHz	
"H" level minimum clock pulse width	tw +	16.0	_	_	ns	
"L" level minimum clock pulse width	tw -	16.0	_	_	ns	
Operating temperature range	Та	-20	_	+75	°C	

**WARNING:** The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

### ELECTRICAL CHARACTERISTICS

#### 1. DC Characteristics in Analog Section

Deremet	Cumb al	Value				
Parameter		Symbol	Min.	Тур.	Max.	Unit
Resolution		—	_	8	_	bit
Linearity error	Conditional DC	LE	—	±0.20	±0.40	%
Differential linearity error	precision VRT – VRB = 1.5 V	DLE	—	±0.12	±0.20	%
Analog input capacity		CINA	_	15	_	pF
Reference input voltage (Top side) (VRTC opened)		Vrtc	_	$0.50  imes AV_{DD}$	_	V
Reference output voltage (Top side)		Vrt	_	Vrtc	_	V
Reference current (Bottom side)		Ігв	_	6.5	_	mA
Analog supply current		Aldd	_	14.0	34.0	mA
Digital supply current		DIDD	—	3.0	7.0	mA
Standby supply current		ISTBA	_	100	_	μA
		ISTBD		1		μΑ

#### $(AV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, \text{DV}_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, \text{Ta} = -20^{\circ}\text{C to } +75^{\circ}\text{C})$

#### 2. DC Characteristics in Digital Section

(AV\_{DD} = 2.70 V to 3.60 V, DV\_{DD} = 2.70 V to 3.60 V, Ta =  $-20^{\circ}$ C to  $+75^{\circ}$ C)

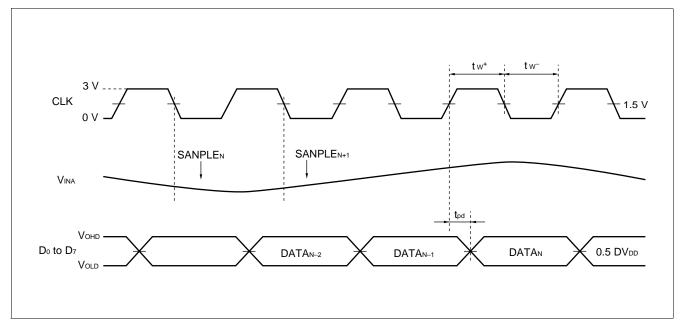
Parameter	Symbol	Value			Unit
Farameter		Min.	Тур.	Max.	Unit
Digital "H" level output voltage	Vонd	2.4	_	DVdd	V
Digital "L" level output voltage	Vold	—	—	0.4	V
Digital "H" level output current	Іонр	-400	—		μA
Digital "L" level output current	IOLD	—	—	1.6	mA

## 3. Switching Characteristics

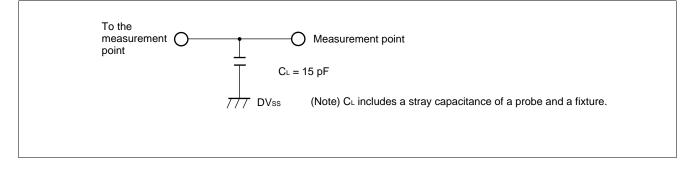
 $(AV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, \text{DV}_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, \text{ Ta} = -20^{\circ}\text{C to } +75^{\circ}\text{C})$ 

Parameter	Symbol	Value			Unit
Falameter		Min.	Тур.	Max.	Unit
Maximum conversion rate	fs	30	—		MSPS
Digital output delay time	t <sub>pd</sub>	3	8	20	ns

#### ■ DIAGRAM



#### ■ DIGITAL OUTPUT BUFFER LOAD CIRCUIT



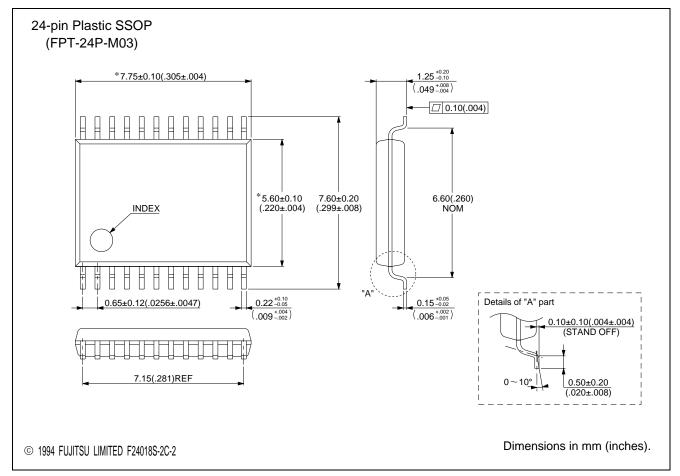
#### ■ USAGE PRECAUTIONS

- Be sure to ground the pins of AV<sub>DD</sub>, DV<sub>DD</sub>, V<sub>RT</sub> and V<sub>RB</sub> via high-frequency capacitor. Place the high-frequency capacitor as close as possible to the pin.
- You can minimize the power supply current dissipation due to the internal logic indetermination by making the clock to 4CLK or higher.

## ■ ORDERING INFORMATION

Part number	Package	Remark
MB40C238PFV	24-pin Plastic SSOP (FPT-24P-M03)	

#### ■ PACKAGE DIMENSION



## MB40C238

# FUJITSU LIMITED

For further information please contact:

#### Japan

FUJITSU LIMITED Corporate Global Business Support Division Electronic Devices KAWASAKI PLANT, 4-1-1, Kamikodanaka Nakahara-ku, Kawasaki-shi Kanagawa 211-8588, Japan Tel: 81(44) 754-3763 Fax: 81(44) 754-3329

http://www.fujitsu.co.jp/

#### North and South America

FUJITSU MICROELECTRONICS, INC. Semiconductor Division 3545 North First Street San Jose, CA 95134-1804, USA Tel: (408) 922-9000 Fax: (408) 922-9179

Customer Response Center *Mon. - Fri.: 7 am - 5 pm (PST)* Tel: (800) 866-8608 Fax: (408) 922-9179

http://www.fujitsumicro.com/

#### Europe

FUJITSU MIKROELEKTRONIK GmbH Am Siebenstein 6-10 D-63303 Dreieich-Buchschlag Germany Tel: (06103) 690-0 Fax: (06103) 690-122

http://www.fujitsu-ede.com/

#### Asia Pacific

FUJITSU MICROELECTRONICS ASIA PTE LTD #05-08, 151 Lorong Chuan New Tech Park Singapore 556741 Tel: (65) 281-0770 Fax: (65) 281-0220

http://www.fmap.com.sg/

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